



## QUICKSWITCH® PRODUCTS 3.3V HIGH SPEED 32-BIT MULTIWIDHT™ BUS SWITCH

IDTQS34XV245

### FEATURES:

- $5\Omega$  bidirectional switches connect inputs to outputs
- Pin compatibility with QS3245
- 250ps propagation delay
- Undershoot clamp diodes on all switch and control inputs
- LVTTL-compatible control inputs
- Available in 80-pin QVSOP package

### APPLICATIONS:

- 3.3V to 2.5V Voltage translation
- 2.5V to 1.8V Voltage translation
- PCI bus isolation hot swap

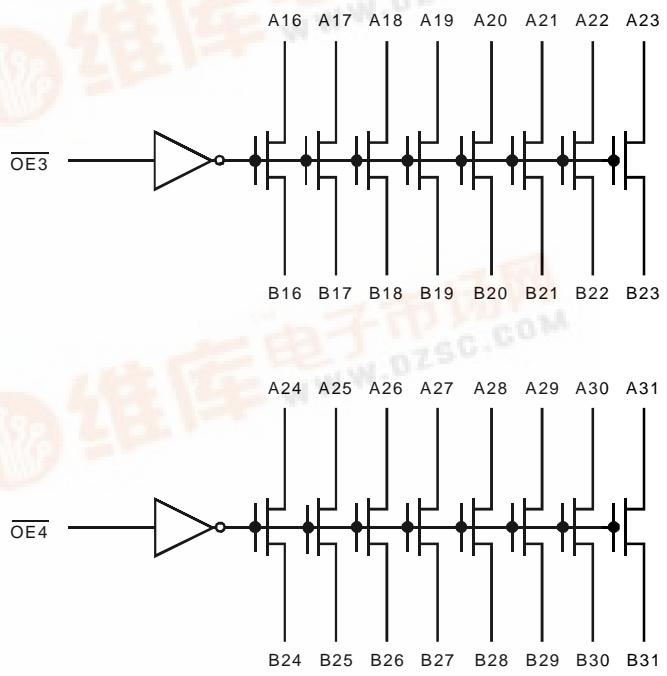
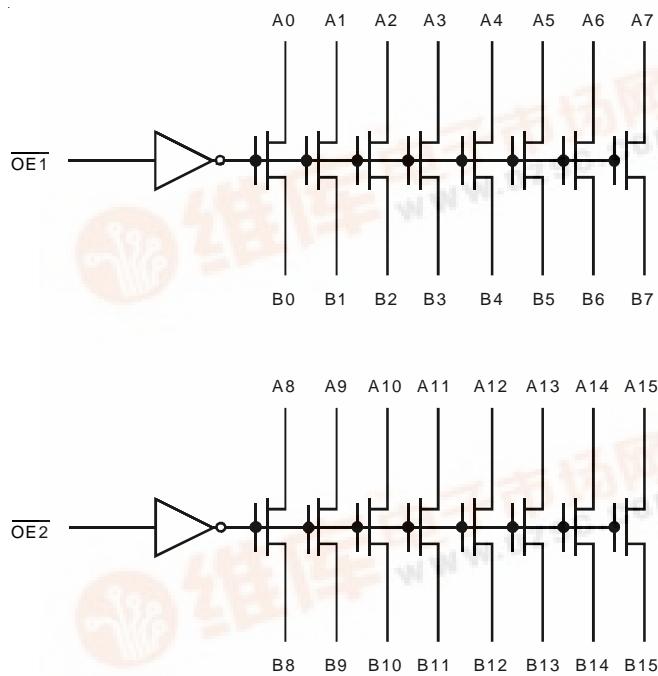
### DESCRIPTION:

The QS34XV245 is a set of 32-bit high speed bus switches controlled by LVTTL-compatible active low enable signal. When closed, the switches exhibit near zero propagation delay without generating additional ground bounce or switching noise.

The QS34XV245 is specially designed for direct interface between 3.3V and 2.5V devices without any external components. When operating from a 3.3V supply, the logic high level at the switch output is clamped to 2.5V when the switch input signal exceeds 2.5V. This device can be used for switching 2.5V buses without signal attenuation. The ON resistance at 3.3V V<sub>cc</sub> is less than  $5\Omega$  typical, providing near zero propagation delay through the switch. Absence of DC path from switch I/O pins to V<sub>cc</sub> or ground makes QS34XV245 an ideal device for hot swapping applications.

The QS34XV245 is characterized for operation from -40°C to +85°C.

### FUNCTIONAL BLOCK DIAGRAM



## PIN CONFIGURATION

NC	1	Vcc
A0	2	$\overline{OE}_1$
A1	3	B0
A2	4	B1
A3	5	B2
A4	6	B3
A5	7	B4
A6	8	B5
A7	9	B6
GND	10	B7
NC	11	Vcc
A8	12	$\overline{OE}_2$
A9	13	B8
A10	14	B9
A11	15	B10
A12	16	B11
A13	17	B12
A14	18	B13
A15	19	B14
GND	20	B15
NC	21	Vcc
A16	22	$\overline{OE}_3$
A17	23	B16
A18	24	B17
A19	25	B18
A20	26	B19
A21	27	B20
A22	28	B21
A23	29	B22
GND	30	B23
NC	31	Vcc
A24	32	$\overline{OE}_4$
A25	33	B24
A26	34	B25
A27	35	B26
A28	36	B27
A29	37	B28
A30	38	B29
A31	39	B30
GND	40	B31

MILLIPAQ  
TOP VIEWABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Supply Voltage to Ground	-0.5 to +4.6	V
VTERM <sup>(3)</sup>	DC Switch Voltage Vs	-0.5 to +4.6	V
VTERM <sup>(3)</sup>	DC Input Voltage V <sub>IN</sub>	-0.5 to +4.6	V
VAC	AC Input Voltage (pulse width $\leq$ 20ns)	-3	V
I <sub>OUT</sub>	DC Output Current	120	mA
P <sub>MAX</sub>	Maximum Power Dissipation (TA = 85°C)	0.92	W
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

## NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc.

## CAPACITANCE

(TA = +25°C, f = 1.0MHz, V<sub>IN</sub> = 0V, V<sub>OUT</sub> = 0V)

Pins	Typ.	Max. <sup>(1)</sup>	Unit
Control Pins	4	6	pF
Quickswitch Channels (Switch OFF)	5	7	pF

## NOTE:

1. This parameter is measured at characterization but not tested.

## PIN DESCRIPTION

Pin Names	Description
$\overline{OE}$	Output Enable
An, Bn	Data I/Os

FUNCTION TABLE<sup>(1)</sup>

$\overline{OE_n}$	Function
H	Disconnected
L	An = Bn

## NOTE:

1. H = HIGH Voltage Level  
L = LOW Voltage Level

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: TA = -40°C to +85°C, VCC = 3.3V ± 0.3V

Symbol	Parameter	Test Conditions	Min.	Typ. <sup>(1)</sup>	Max.	Unit
V <sub>IH</sub>	Input HIGH Level	Guaranteed Logic HIGH for Control Pins	2	—	—	V
V <sub>IL</sub>	Input LOW Level	Guaranteed Logic LOW for Control Pins	—	—	0.8	V
I <sub>IN</sub>	Input Leakage Current (Control Inputs)	0V ≤ V <sub>IN</sub> ≤ V <sub>CC</sub>	—	—	1	μA
I <sub>OZ</sub>	Off-State Output Current (Hi-Z)	0V ≤ V <sub>OUT</sub> ≤ V <sub>CC</sub> , Switches OFF	—	0.001	1	μA
R <sub>ON</sub>	Switch ON Resistance	V <sub>CC</sub> = Min., V <sub>IN</sub> = 0V, I <sub>ON</sub> = 8mA	—	5	7	Ω
		V <sub>CC</sub> = Min., V <sub>IN</sub> = 1.7V, I <sub>ON</sub> = 8mA	—	15	20	
		V <sub>CC</sub> = 2.3V, V <sub>IN</sub> = 0V, I <sub>ON</sub> = 8mA	—	7	—	
		V <sub>CC</sub> = 2.3V, V <sub>IN</sub> = 1.3V, I <sub>ON</sub> = 8mA	—	25	—	
V <sub>P</sub>	Pass Voltage <sup>(2)</sup>	V <sub>IN</sub> = V <sub>CC</sub> = 3.3V, I <sub>OUT</sub> = -5μA	2.5	2.7	2.9	V
		V <sub>IN</sub> = V <sub>CC</sub> = 2.5V, I <sub>OUT</sub> = -5μA	—	1.8	—	

NOTES:

1. Typical values are at V<sub>CC</sub> = 3.3V, TA = 25°C.

2. Pass Voltage is guaranteed but not production tested.

## POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>	Max.	Unit
I <sub>CCQ</sub>	Quiescent Power Supply Current	V <sub>CC</sub> = Max., V <sub>IN</sub> = GND or V <sub>CC</sub> , f = 0	12	μA
ΔI <sub>CC</sub>	Power Supply Current per Control Input HIGH <sup>(2)</sup>	V <sub>CC</sub> = Max., V <sub>IN</sub> = 3V or V <sub>CC</sub> , f = 0	50	μA
I <sub>CCD</sub>	Dynamic Power Supply Current per MHz <sup>(3)</sup>	V <sub>CC</sub> = Max., A and B pins open Control Inputs Toggling at 50% Duty Cycle	0.15	mA/MHz

NOTES:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.

2. Per TLL driven input (V<sub>IN</sub> = 3.4V, control inputs only). A and B pins do not contribute to ΔI<sub>CC</sub>.

3. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

## SWITCHING CHARACTERISTICS OVER OPERATING RANGE

$T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ ,  $V_{CC} = 3.3\text{V} \pm 0.3\text{V}$ ;

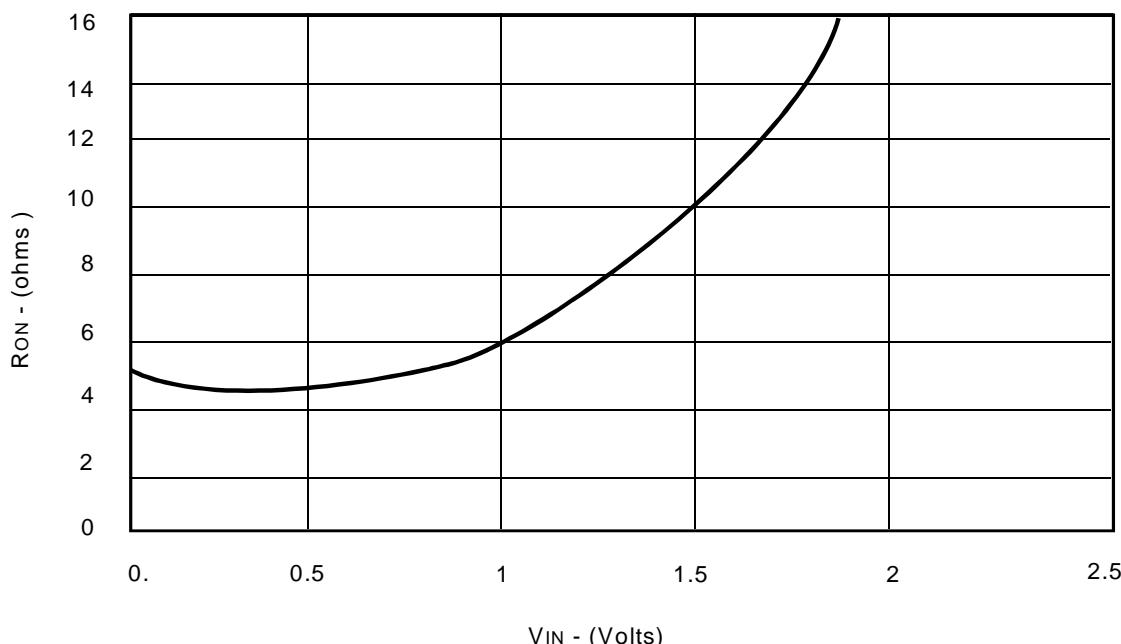
$C_{LOAD} = 50\text{pF}$ ,  $R_{LOAD} = 500\Omega$  unless otherwise noted.

Symbol	Parameter	Min. <sup>(1)</sup>	Typ.	Max.	Unit
$t_{PLH}$	Data Propagation Delay <sup>(2,3)</sup> An to/from Bn	—	—	0.25	ns
$t_{PZL}$	Switch Turn-on Delay $\overline{OEn}$ to An/Bn	0.5	—	6.5	ns
$t_{PLZ}$	Switch Turn-off Delay <sup>(2)</sup> $\overline{OEn}$ to An/Bn	0.5	—	4	ns

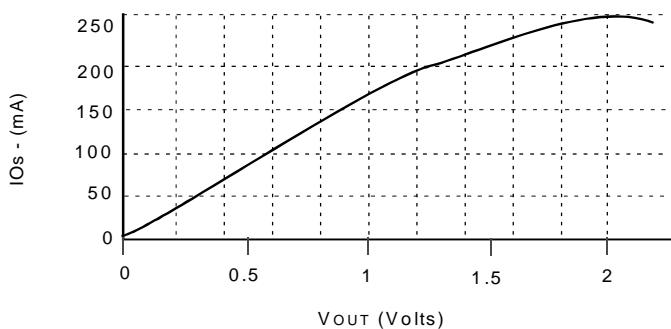
### NOTES:

1. Minimums are guaranteed but not production tested.
2. This parameter is guaranteed but not production tested.
3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns for  $C_L = 30\text{pF}$ . Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

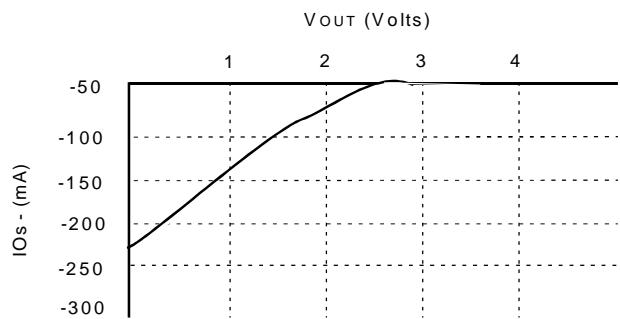
## TYPICAL ON RESISTANCE vs VIN AT VCC = 3.3V



## OUTPUT VI CHARACTERISTICS

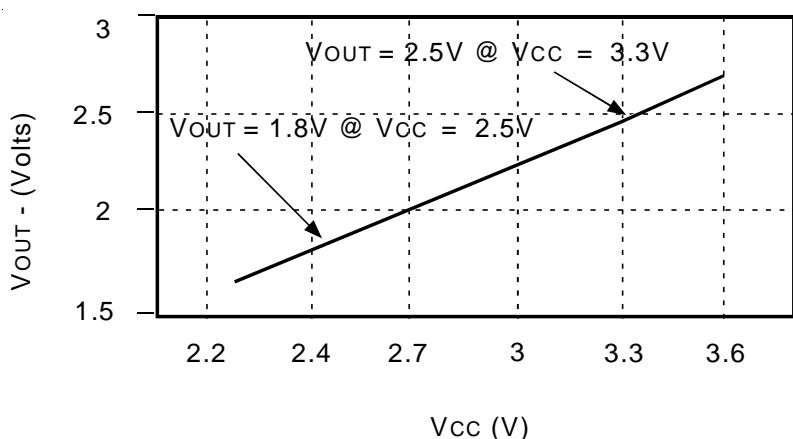


*Outputs Low Characteristic*

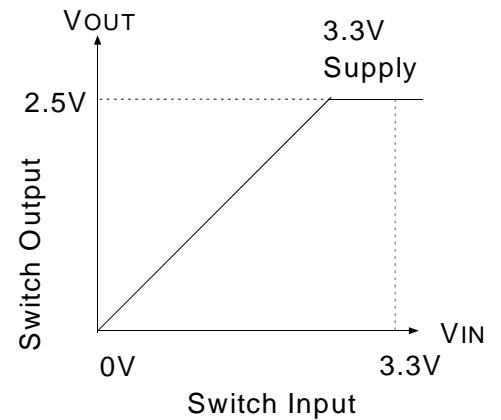
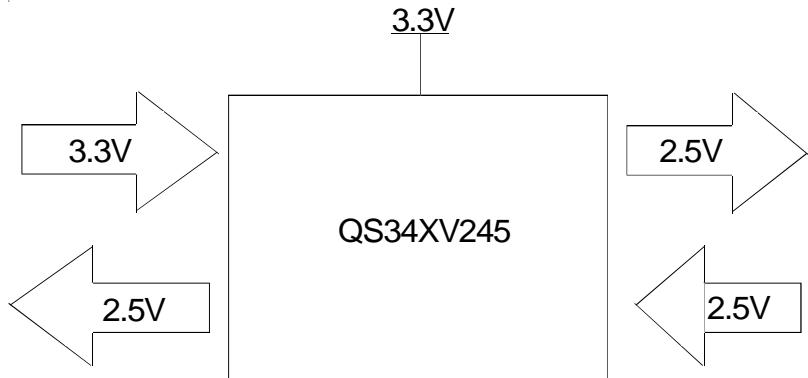


*Outputs High Characteristic*

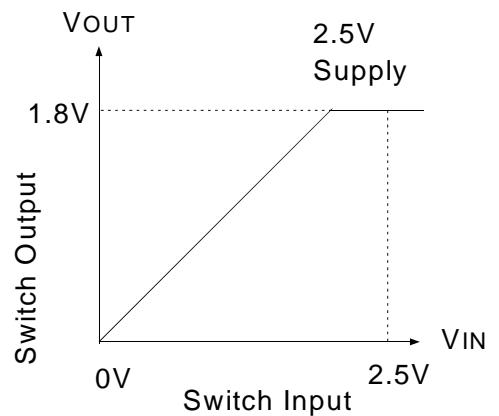
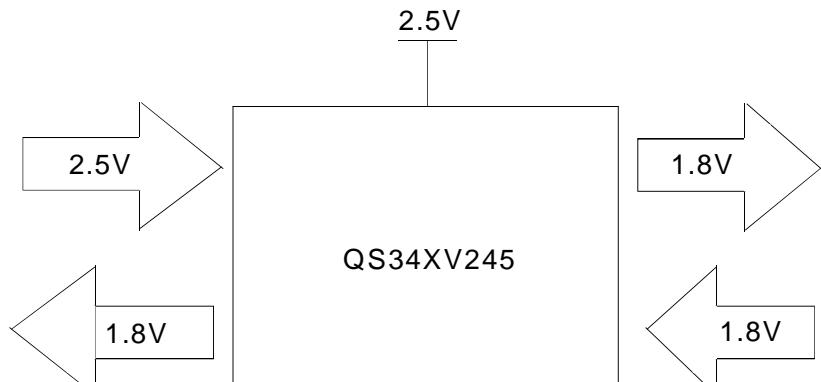
## PASS VOLTAGE vs VCC



### 3.3V TO 2.5V VOLTAGE TRANSLATION



### 2.5V TO 1.8V VOLTAGE TRANSLATION



## ORDERING INFORMATION

IDTQS	XXXXX	XX	X		
Device Type		Package	Process		
			Blank	Industrial (-40°C to +85°C)	
			Q3	80-Pin MillipaQ	
			34XV245	3.3V High Speed 32-Bit Multiwidth Bus Switch	



**CORPORATE HEADQUARTERS**  
2975 Stender Way  
Santa Clara, CA 95054

*for SALES:*  
800-345-7015 or 408-727-6116  
fax: 408-492-8674  
[www.idt.com](http://www.idt.com)

*for Tech Support:*  
[logichelp@idt.com](mailto:logichelp@idt.com)  
(408) 654-6459